

DFM1200EXM18-A000

Fast Recovery Diode Module

Replaces DS5913-2 DS5913-3 August 2017 (LN34661)

FEATURES

- Low Reverse Recovery Charge
- **High Switching Speed**
- Low Forward Volt Drop
- Isolated AlSiC Base with AlN Substrates
- Triple Diodes can be paralleled for 3600A rating
- Lead Free Construction

APPLICATIONS

- **Chopper Diodes**
- **Boost and Buck Circuits**
- Free-wheel Circuits
- Multi-level Switch Inverters

The DFM1200EXM18-A000 is a triple 1800V, fast recovery diode (FRD) module. Designed for low power loss, the module is suitable for a variety of high voltage applications in motor drives and power conversion.

Fast switching times and low reverse recovery losses allow high frequency operation, making the device suitable for the latest drive designs employing PWM and high frequency switching.

The module incorporates an electrically isolated base plate and low inductance construction enabling circuit designers to optimise circuit layouts and utilise grounded heat sinks for safety.

ORDERING INFORMATION

Order As:

DFM1200EXM18-A000

Note: When ordering, please use the complete part number

KEY PARAMETERS

V_{RRM}		1800V
V_{F}	(typ)	2.0V
I _F	(max)	1200A
I _{FM}	(max)	2400A

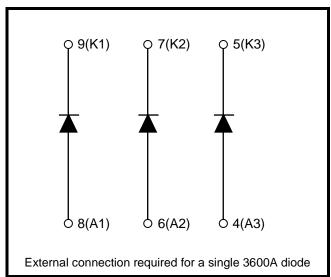


Fig. 1 Circuit configuration

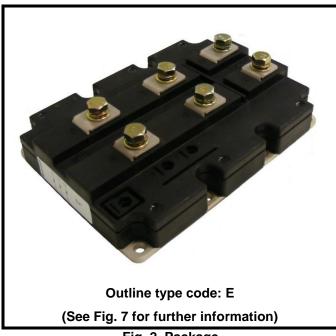


Fig. 2 Package



ABSOLUTE MAXIMUM RATINGS - PER ARM

Stresses above those listed under 'Absolute Maximum Ratings' may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed. Exposure to Absolute Maximum Ratings may affect device reliability.

T_{case} = 25°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
V_{RRM}	Repetitive peak reverse voltage	T _j = 125°C	1800	V
I _F	Forward current	DC, T _{case} = 75°C, T _j = 125°C	1200	Α
I _{FM}	Max. forward current	$T_{case} = 110$ °C, $t_p = 1$ ms	2400	Α
l ² t	I ² t value fuse current rating	$V_R = 0$, $t_p = 10$ ms, $T_j = 125$ °C	480	kA ² s
P _{max}	Max. transistor power dissipation	$T_{case} = 25^{\circ}C, T_{j} = 125^{\circ}C$	5000	W
V _{isol}	Isolation voltage – per module	Commoned terminals to base plate. AC RMS, 1 min, 50Hz	4000	V
Q_{PD}	Partial discharge – per module	IEC1287, V ₁ = 1900V, V ₂ = 1400V, 50Hz RMS	10	рC

THERMAL AND MECHANICAL RATINGS

Internal insulation material:

Baseplate material:

Creepage distance:

Clearance:

CTI (Comparative Tracking Index):

AIN

AISiC

33mm

20mm

>600

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Units
R _{th(j-c)}	Thermal resistance (per arm)	Continuous dissipation – junction to case	-	-	20	°C/kW
R _{th(c-h)}	Thermal resistance – case to heatsink (per module)	Mounting torque 5Nm (with mounting grease)	ı	ı	6	°C/kW
T_j	Junction temperature		-	-	125	°C
T _{stg}	Storage temperature range		-40	-	125	°C
	Coroux Torque	Mounting – M6	-	-	5	Nm
	Screw Torque	Electrical connections – M8	-	-	10	Nm



STATIC ELECTRICAL CHARACTERISTICS - PER ARM

 T_{case} = 25°C unless stated otherwise.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
I _{RM}	Peak reverse current	V _R = 1800V, T _j = 125°C			20	mA
V _F	Forward voltage	I _F = 1200A		2.0	2.3	V
		I _F = 1200A, T _j = 125°C		2.0	2.3	V
L _M	Inductance			20		nΗ

STATIC ELECTRICAL CHARACTERISTICS

 T_{case} = 25°C unless stated otherwise.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
L_M	Module inductance (externally connected in parallel)			15		nΗ

DYNAMIC ELECTRICAL CHARACTERISTICS - PER ARM

T_{case} = 25°C unless stated otherwise

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Units
Q_{rr}	Reverse recovery charge	$I_F = 1200A$ $V_R = 900V$ $dI_F/dt = 8000A/\mu s$		320		μC
I _{rr}	Peak reverse recovery current			880		Α
E _{rec}	Reverse recovery energy			240		mJ

T_{case} = 125°C unless stated otherwise

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Units
Q_{rr}	Reverse recovery charge	$I_F = 1200A$ $V_R = 900V$ $dI_F/dt = 8000A/\mu s$		540		μC
I _{rr}	Peak reverse recovery current			1020		Α
E _{rec}	Reverse recovery energy			360		mJ



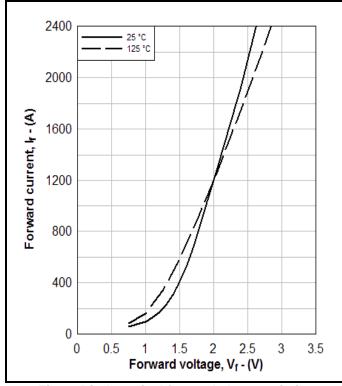


Fig. 3 Diode typical forward characteristics

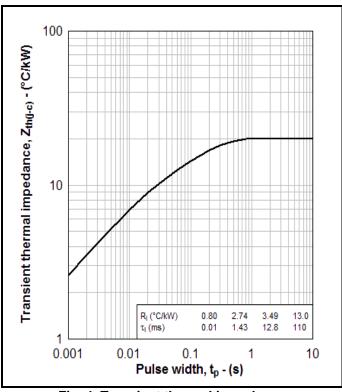


Fig. 4 Transient thermal impedance

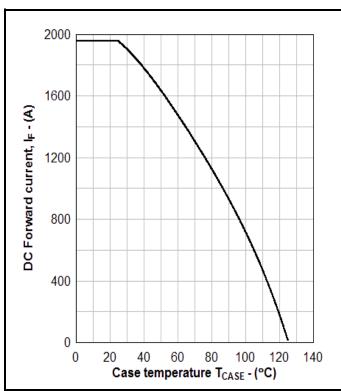


Fig. 5 DC Current rating vs case temperature

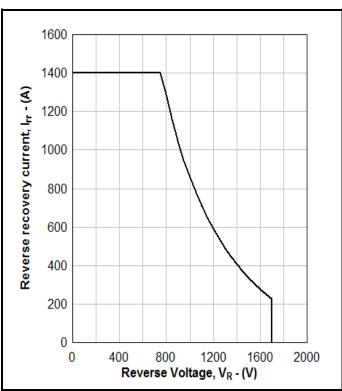


Fig. 6 RBSOA



PACKAGE DETAILS

For further package information, please visit our website or contact Customer Services. All dimensions in mm, unless stated otherwise.

DO NOT SCALE.

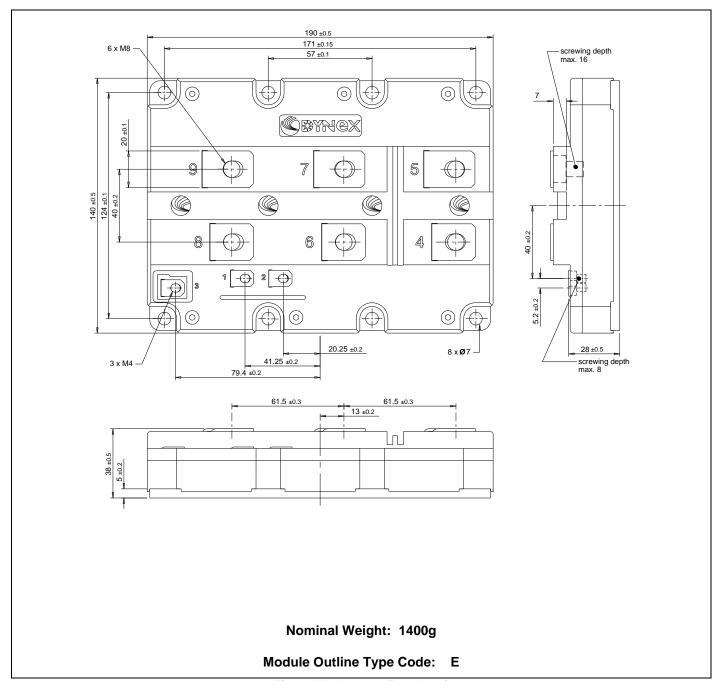


Fig. 7 Module outline drawing



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HEADQUARTERS OPERATIONS

DYNEX SEMICONDUCTOR LTD

Doddington Road, Lincoln, Lincolnshire, LN6 3LF, United Kingdom

Fax: +44(0)1522 500550 Tel: +44(0)1522 500500

Tel: +44(0)1522 500500 Web: http://www.dynexsemi.com

CUSTOMER SERVICE

DYNEX SEMICONDUCTOR LTD

Doddington Road, Lincoln, Lincolnshire, LN6 3LF, United Kingdom

Fax: +44(0)1522 500020

Tel: +44(0)1522 502753 / 502901 Email: <u>Power_solutions@dynexsemi.com</u>

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